TOSHIBA Photocoupler GaAlAs Ired & Photo IC

# 6N138, 6N139

Current Loop Driver.

Low Input Current Line Receiver.

CMOS Logic Interface.

The TOSHIBA 6N138 and 6N139 consists of a GaA $\ell$ As infrared

emitting diode coupled with a split-Darlington output configuration.

A high speed GaAlAs Ired manufactured with an unique LPE junction, has the virtue of fast rise and fall time at low drive current.

- · Isolation voltage: 2500Vrms (min.)
- · Current transfer ratio

: 6N138 - 300% (min.) (IF=1.6mA)

: 6N139 - 400% (min.) (IF=0.5mA)

· Switching time: 6N138 - tPHL=10µs (max.)

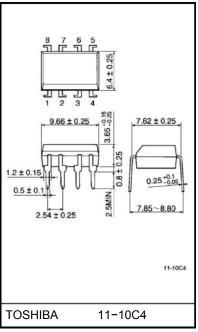
- tPLH=35μs (max.)

 $6N139 - tPHL=1\mu s (max.)$ 

- tPLH=7µs (max.)

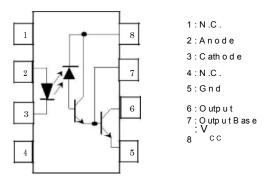
· UL recognized: UL1577, file no. E67349

Unit in mm

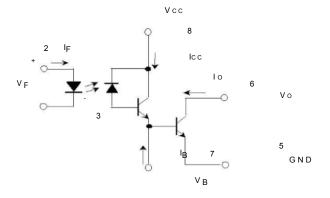


Weight: 0.54 g

#### Pin Configuration (top view)



#### **Schematic**





## Maximum Ratings (\*) (Ta = 0°C to + 70°C)

	Characteristic		Symbol	Rating	Unit
	Forward current	(Note 1)	lF	20	mA
	Pulse forward current		IFP <sup>(*1)</sup>	40	mA
쁘	Total pulse forward current		IFP <sup>(*2)</sup>	1	Α
	Reverse voltage		۷R	5	V
	Diode power dissipation	(Note 2)	PD	35	mW
	Output current	(Note 3)	10	60	mA
_	Emitter-base reverse voltage		<b>V</b> EB	0.5	V
Detector	Supply voltage		ACC <sub>(*3)</sub>	-0.5 to 18	V
Pe	Output voltage		VO(*3)	-0.5 to 18	V
	Output power dissipation	(Note 4)	РО	100	mW
Оре	erating temperature range		opr	0 to 70	°C
Sto	rage temperature range		stg	-55 to 125	°C
Lea	d solder temperature (10s) (*4)		sol	260	°C
			D\/C(**)	2500	v rms
ISOI	ation voltage (1min., R.H.≤ 60%)		BVs(**)	3540	<b>V</b> dc

<sup>(\*)</sup> JEDEC registered data

<sup>(\*\*)</sup> Not registered JEDEC

<sup>(\*1) 50%</sup> duty cycle, 1ms pulse width

<sup>(\*2)</sup> Pulse width 1µs, 300pps

<sup>(\*3) 6</sup>N138... -0.5 to 7V

<sup>(\*4) 1.6</sup>mm below seating plane



## Electrical Characteristics Over Recommended Temperature (Ta = 0°C to 70°C, unless otherwise noted)

Characteristic		Symbol	Test Condition	Min.	(*5)Typ.	Max.	Unit	
Current transfer	6N139 6N138	OTD (1)	IF=0.5mA, VO=0.4V VCC=4.5V	400	800	3/4	- %	
ratio (Note 5, 6)		CTR(*)	IF=1.6mA, VO=0.4V	500	900	3/4	70	
			V <sub>CC</sub> =4.5V	300	600	3/4		
	6N139	V	IF=1.6mA, IO=6.4mA VCC=4.5V	3/4	0.1	0.4		
Logic low output			IF=5mA, I <sub>O</sub> =15mA <sub>V<sub>CC</sub>=4.5V</sub>	3/4	0.1	0.4		
voltage (Note 6)		V OL	IF=12mA, I O=24mA V <sub>CC</sub> =4.5V	3/4	0.2	0.4	V	
	6N138		IF=1.6mA, IO=4.8mA VCC=4.5V	3/4	0.1	0.4		
Logic high output	6N139	IOH(*)	IF=0mA, VO=VCC=18V	3/4	0.05	100		
current (Note 6)	6N138		IF=0mA, VO=VCC=7V	3/4	0.05	250	μA	
Logic low supply current (Note 6)		l CCL	IF=1.6mA, VO=Open VCC=5V	3/4	0.2	3/4	mA	
Logic high supply current (Note 6)		I CCH	IF=0mA, VO=Open, VCC=5V	3/4	10	3/4	nA	
Input forward voltage		VF(*)	IF=1.6mA, Ta=25°C	3/4	1.65	1.7	V	
Input reverse breakdown voltage		BVR(*)	IR=10μA, Ta=25°C	5	3/4	3/4	V	
Temperature coefficient of forward voltage		ΔVF / ΔTa	IF=1.6mA	3/4	-1.9	3/4	mV / °C	
Input capacitance		OIN	f=1MHz, VF=0	3/4	60	3/4	pF	
Resistance (input-output)		R <sub>I-O</sub>	V <sub>I-O</sub> =500V (Note 7), R.H.≤ 60%	3/4	12 10	3/4	Ω	
Capacitance (input-output)		1-0	f=1MHz (Note 7)	3/4	0.6	3/4	pF	

<sup>(\*\*)</sup> JEDEC registered data.

<sup>(\*5)</sup> All typicals at Ta=25°C and  $V_{CC}$ =5V, unless otherwise noted.



## Switching Specifications (Ta=25°C, V<sub>CC</sub>=5V, unless otherwise specified)

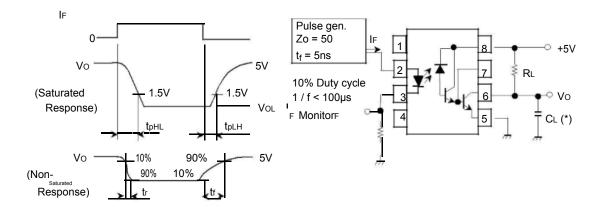
Characteristic		Symbol	Test Circuit	Test Condition	Min.	Тур.	Max.	Unit	
Propagation delay	6N139			IF=0.5mA, RL=4.7kΩ	3/4	5	25		
time to logic low		tpHL(*)	1	1 $I_F=12\text{mA}, R_L=270\Omega$	3/4	0.2	1	ms	
at output (Note 6, 8)	6N138			IF=1.6mA, RL=2.2kΩ	3/4	1	10		
Propagation delay	6N139			I <sub>F</sub> =0.5mA, R <sub>L</sub> =4.7kΩ	3/4	5	60		
time to logic high	t <sub>pLH</sub> (*)	1	$I_F$ =12mA, $R_L$ =270 $\Omega$	3/4		7	ms		
at output (Note 6, 8)	6N138			IF=1.6mA, RL=2.2kΩ	3/4	4	35		
Common mode transient immunity at logic high		СМН	2	IF=0mA, RL=2.2kΩ	3/4	500	3/4	V / ms	
level output (Note 9)				V <sub>CM</sub> =400V <sub>p-p</sub>					
Common mode transient immunity at logic low		CML	2	I <sub>F</sub> =1.6mA R <sub>L</sub> =2.2kΩ	3/4	-500	3/4	V / ms	
level output (Not				∨ <sub>CM</sub> =400∨ <sub>p-p</sub>					

(\*)JEDEC registered data.

- (Note 1): Derate linearly above 50°C free-air temperature at a rate of 0.4mA / °C
- (Note 2): Derate linearly above 50°C free-air temperature at a rate of 0.7mW / °C
- (Note 3): Derate linearly above 25°C free-air temperature at a rate of 0.7mA / °C
- (Note 4): Derate linearly above 25°C free-air temperature at a rate of 2.0mW / °C
- (Note 5): DC CURRENT TRANSFER RATIO is defined as the ratio of output collector current, I<sub>O</sub>, to the forward LED input current, I<sub>F</sub>, times 100%.
- (Note 6): Pin 7 open.
- (Note 7): Device considered a two-terminal device: Pins 1, 2, 3, and 4 shorted together and Pins 5, 6, 7 and 8 shorted together.
- (Note 8): Use of a resistor between pin 5 and 7 will decrease gain and delay time.
- (Note 9): Common mode transient immunity in logic high level is the maximum tolerable (positive) dv<sub>CM</sub> / dt on the leading edge of the common mode pulse, V<sub>CM</sub>, to assure that the output will remain in a logic high state (i.e., V<sub>O</sub> > 2.0V). Common mode transient immunity in Logic Low level is the maximum tolerable (negative) dv<sub>CM</sub> / dt on the trailing edge of the common mode pulse signal, V<sub>CM</sub>, to assure that the output will remain in a logic low state (i.e., V<sub>O</sub> < 0.8V).

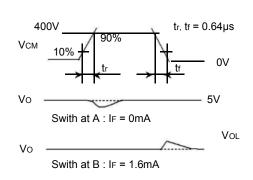
#### **Test Circuit 1.**

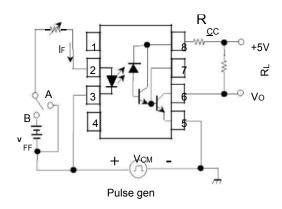
TOSHIBA



(\*)CL is approximately 15pF which includes probe and stray wiring capacitance.

#### **Test Circuit 2.**





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